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REVISION HISTORY

5/13—Rev. C to Rev. D

Changes to Table 1	3
Changes to Ordering Guide	11

12/11—Rev. B to Rev. C

Updated Format	Universal
Added Figure 1, Renumbered Sequentially	1
Deleted Chip Dimensions and Pad Layout Section	5
Changes to Figure 3 and Figure 4	6
Added Table 3 and Table 4	6
Changes to the Operations as a Divider Section	9
Updated Outline Dimensions	10

4/10—Rev. A to Rev. B

Changes to Pin Configurations and Product Highlights	
Sections	1
Changes to Thermal Characteristics Section	3
Updated Outline Dimensions	6
Changes to Ordering Guide	6

SPECIFICATIONS

@ +25°C, $V_S = \pm 15\text{ V}$, $R \geq 2\text{ k}\Omega$, unless otherwise noted. Specifications shown in boldface are tested on all production units at final electrical test. Results from those tests are used to calculate outgoing quality levels.

Table 1.

Parameter	AD632A			AD632B			AD632S			AD632T			Units
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
MULTIPLIER PERFORMANCE													
Transfer Function	$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10\text{ V}} + Z_2$			$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10\text{ V}} + Z_2$			$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10\text{ V}} + Z_2$			$\frac{(X_1 - X_2)(Y_1 - Y_2)}{10\text{ V}} + Z_2$			
Total Error ¹ ($-10\text{ V} \leq X, Y \leq +10\text{ V}$)			±1.0			±0.5			±1.0			±0.5	%
$T_A = \text{Min to Max}$		±1.5			±1.0			±2.0			±1.0		%
Total Error vs. Temperature		±0.022			±0.015			±0.02			±0.01		%/°C
Scale Factor Error (SF = 10,000 V Nominal) ²		±0.25			±0.1			±0.25			±0.1		%
Temperature Coefficient of Scaling Voltage		±0.02			±0.01			±0.2			±0.005		%/°C
Supply Rejection ($\pm 15\text{ V} \pm 1\text{ V}$)		±0.01			±0.01			±0.01			±0.01		%
Nonlinearity													
X ($X = 20\text{ V p-p}, Y = 10\text{ V}$)		±0.4			±0.2	±0.3		±0.4			±0.2	±0.3	%
Y ($Y = 20\text{ V p-p}, X = 10\text{ V}$)		±0.2			±0.1	±0.1		±0.2			±0.1	±0.1	%
Feedthrough ³													
X (Y Nulled, $X = 20\text{ V p-p } 50\text{ Hz}$)		±0.3			±0.15	±0.3		±0.3			±0.15	±0.3	%
Y (X Nulled, $Y = 20\text{ V p-p } 50\text{ Hz}$)		±0.01			±0.01	±0.1		±0.01			±0.01	±0.1	%
Output Offset Voltage		±5	±30		±2	±15		±5	±30		±2	±15	mV
Output Offset Voltage Drift		200			100				500			300	μV/°C
DYNAMICS													
Small Signal BW, ($V_{OUT} = 0.1\text{ rms}$)		1			1			1			1		MHz
1% Amplitude Error ($C_{LOAD} = 1000\text{ pF}$)		50			50			50			50		kHz
Slew Rate ($V_{OUT} 20\text{ p-p}$)		20			20			20			20		V/μs
Settling Time (to 1%, $\Delta V_{OUT} = 20\text{ V}$)		2			2			2			2		μs
NOISE													
Noise Spectral Density													
SF = 10 V		0.8			0.8			0.8			0.8		μV/√Hz
SF = 3 V ⁴		0.4			0.4			0.4			0.4		μV/√Hz
Wideband Noise													
A = 10 Hz to 5 MHz		1.0			1.0			1.0			1.0		mV/rms
P = 10 Hz to 10 kHz		90			90			90			90		μV/rms
OUTPUT													
Output Voltage Swing	±11			±11			±11			±11			V
Output Impedance ($f \leq 1\text{ kHz}$)		0.1			0.1			0.1			0.1		Ω
Output Short-Circuit Current ($R_L = 0, T_A = \text{Min to Max}$)		30			30			30			30		mA
Amplifier Open-Loop Gain ($f = 50\text{ Hz}$)		70			70			70			70		dB
INPUT AMPLIFIERS (X, Y, and Z) ⁵													
Signal Voltage Range (Differential or Common- Mode Operating Diff.)		±10	±12		±10	±12		±10	±12		±10	±12	V
Offset Voltage X, Y		±5	±20		±2	±10		±5	±20		±2	±10	mV
Offset Voltage Drift X, Y		100			50			100			150		μV/°C
Offset Voltage Z		±5	±30		±2	±15		±5	±30		±2	±15	mV
Offset Voltage Drift Z		200			100				500			300	μV/°C
CMRR	60	80		70	90		60	80		70	90		dB
Bias Current		0.8	2.0		0.8	2.0		0.8	2.0		0.8	2.0	μA
Offset Current		0.1			0.1			0.1			0.1		μA
Differential Resistance		10			10			10			10		MΩ

Parameter	AD632A			AD632B			AD632S			AD632T			Units
	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
DIVIDER PERFORMANCE													
Transfer Function ($X_1 > X_2$)	$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_I$			$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_I$			$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_I$			$10V \frac{(Z_2 - Z_1)}{(X_1 - X_2)} + Y_I$			
Total Error ¹													
($X = 10\text{ V}, -10\text{ V} \leq Z \leq +10\text{ V}$)	±0.75			±0.35			±0.75			±0.35			%
($X = 1\text{ V}, -1\text{ V} \leq Z \leq +1\text{ V}$)	±2.0			±1.0			±2.0			±1.0			%
($0.1\text{ V} \leq X \leq 10\text{ V}, -10\text{ V} \leq Z \leq 10\text{ V}$)	±2.5			±1.0			±2.5			±1.0			%
SQUARER PERFORMANCE													
Transfer Function	$\frac{(X_1 - X_2)^2}{10\text{ V}} + Z_2$			$\frac{(X_1 - X_2)^2}{10\text{ V}} + Z_2$			$\frac{(X_1 - X_2)^2}{10\text{ V}} + Z_2$			$\frac{(X_1 - X_2)^2}{10\text{ V}} + Z_2$			
Total Error ($-10\text{ V} \leq X \leq 10\text{ V}$)	±0.6			±0.3			±0.6			±0.3			%
SQUARE-ROOTER PERFORMANCE													
Transfer Function, ($Z_1 \leq Z_2$)	$\sqrt{10\text{ V}(Z_2 - Z_1) + X_2}$			$\sqrt{10\text{ V}(Z_2 - Z_1) + X_2}$			$\sqrt{10\text{ V}(Z_2 - Z_1) + X_2}$			$\sqrt{10\text{ V}(Z_2 - Z_1) + X_2}$			
Total Error ¹ ($1\text{ V} \leq Z \leq 10\text{ V}$)	±1.0			±0.5			±1.0			±0.5			%
POWER SUPPLY SPECIFICATIONS													
Supply Voltage													
Rated Performance	±15			±15			±15			±15			V
Operating	±8		±18	±8		±18	±8		±22	±8		±22	V
Supply Current													
Quiescent	4	6		4	6		4	6		4	6		mA

¹ Figures given are percent of full-scale, $\pm 10V$ (that is, $0.01\% = 1mV$).

² Can be reduced to 3V using an external resistor between $-V_S$ and SF.

³ Irreducible component due to nonlinearity; excludes effect of offsets.

⁴ Using an external resistor adjusted to give a value of SF = 3V.

⁵ See the functional block diagram (Figure 1) for definition of sections.

ABSOLUTE MAXIMUM RATINGS

THERMAL RESISTANCE

θ_{JA} is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 2. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
10-Lead TO-100	150	25	°C/W
14-Lead SBDIP	95	25	°C/W

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

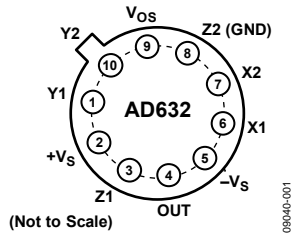


Figure 2. Pin Configuration, H-Package, TO-100

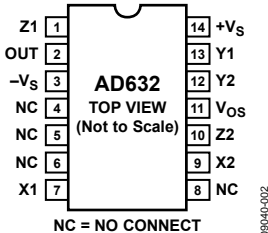


Figure 3. Pin Configuration, D-Package, SBDIP

Table 3. Pin Function Descriptions, 10-Pin TO-100

Pin No.	Mnemonic	Description
1	Y1	Y Multiplicand Noninverting Input.
2	+Vs	Positive Supply Voltage.
3	Z1	Summing Node Noninverting Input.
4	OUT	Product.
5	-Vs	Negative Supply Voltage.
6	X1	X Multiplicand Noninverting Input.
7	X2	X Multiplicand Inverting Input.
8	Z2	Summing Node Inverting Input.
9	Vos	Offset Voltage Adjustment.
10	Y2	Y Multiplicand Inverting Input.

Table 4. Pin Function Descriptions, 14-Lead SBDIP

Pin No.	Mnemonic	Description
1	Z1	Summing Node Noninverting Input.
2	OUT	Product.
3	-Vs	Negative Supply Voltage.
4, 5, 6, 8	NC	No Connection. Do not connect to this pin.
7	X1	X Multiplicand Noninverting Input.
9	X2	X Multiplicand Noninverting Input.
10	Z2	Summing Node Inverting Input.
11	Vos	Offset Voltage Adjustment.
12	Y2	Y Multiplicand Inverting Input.
13	Y1	Y Multiplicand Noninverting Input.
14	+Vs	Positive Supply Voltage.

TYPICAL PERFORMANCE CHARACTERISTICS

Typical @ 25°C with $\pm V_S = 15\text{ V}$.

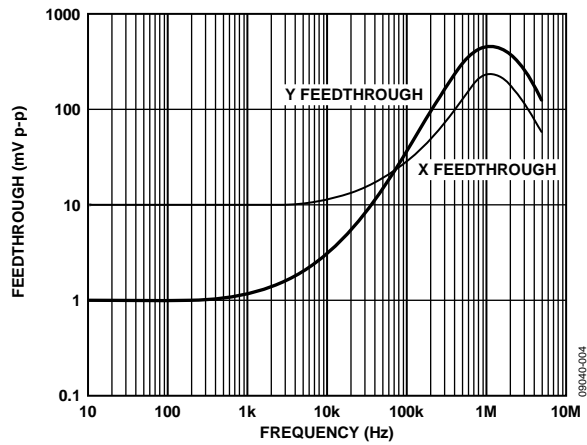


Figure 4. AC Feedthrough vs. Frequency

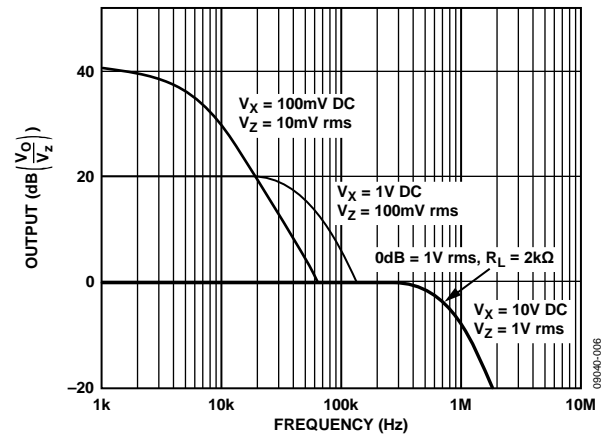


Figure 6. Frequency Response vs. Divider Denominator Input Voltage

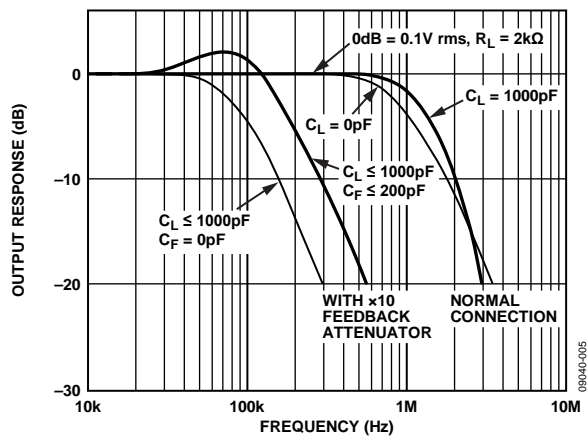


Figure 5. Frequency Response as a Multiplier

OPERATION AS A MULTIPLIER

Figure 7 shows the basic connection for multiplication. Note that the circuit meets all specifications without trimming.

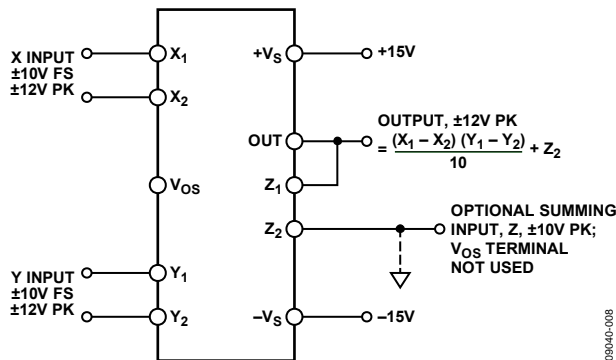


Figure 7. Basic Multiplier Connection

When needed, the user can reduce ac feedthrough to a minimum (as in a suppressed carrier modulator) by applying an external trim voltage (± 30 mV range required) to the X or Y input. Figure 4 shows the typical ac feedthrough with this adjustment mode. Note that the feedthrough of the Y input is a factor of 10 lower than that of the X input and is to be used for applications where null suppression is critical.

The Z_2 terminal of the AD632 can be used to sum an additional signal into the output. In this mode, the output amplifier behaves as a voltage follower with a 1 MHz small signal bandwidth and a 20 V/ μ s slew rate. Always reference this terminal to the ground point of the driven system, particularly if this is remote. Likewise, reference the differential inputs to their respective signal common potentials to realize the full accuracy of the AD632.

A much lower scaling voltage can be achieved without any reduction of input signal range using a feedback attenuator, as shown in Figure 8. In this example, the scale is such that $V_{OUT} = XY$, so that the circuit can exhibit a maximum gain of 10. This connection results in a reduction of bandwidth to about 80 kHz without the peaking capacitor, C_F . In addition, the output offset voltage is increased by a factor of 10 making external adjustments necessary in some applications.

Feedback attenuation also retains the capability for adding a signal to the output. Signals can be applied to the Z terminal, where they are amplified by -10 , or to the common ground connection where they are amplified by -1 . Input signals can also be applied to the lower end of the 2.7 kΩ resistor, giving a gain of $+9$.

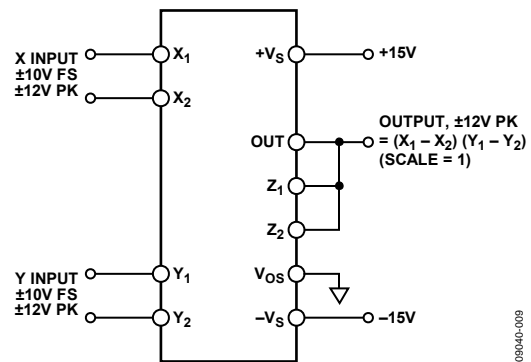


Figure 8. Connections for Scale Factor of Unity

OPERATION AS A DIVIDER

Figure 9 shows the connection required for division. Unlike earlier products, the AD632 provides differential operation on both the numerator and the denominator, allowing the ratio of two floating variables to be generated. Further flexibility results from access to a high impedance summing input to Y_1 . As with all dividers based on the use of a multiplier in a feedback loop, the bandwidth is proportional to the denominator magnitude, as shown in Figure 6.

The accuracy of the AD632 B-model is sufficient to maintain a 1% error over a 10 V to 1 V denominator range.

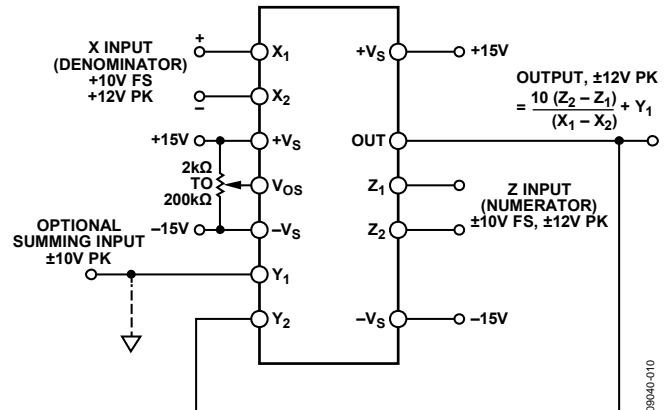
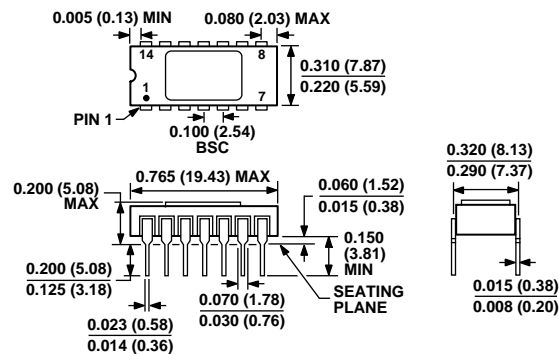


Figure 9. Basic Divider Connection

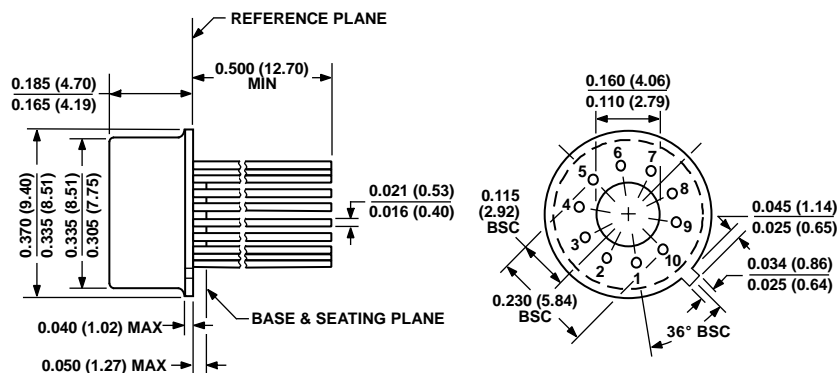
OUTLINE DIMENSIONS



CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 10. 14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP] (D-14)

Dimensions shown in inches and (millimeters)



DIMENSIONS PER JEDEC STANDARDS MO-006-AF
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 11. 10-Pin Metal Header Package [TO-100] (H-10)

Dimensions shown in inches and (millimeters)

022306-A

ORDERING GUIDE

Model ¹	Temperature Range	Package Description	Package Option
AD632AD	–25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632ADZ	–25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632AHZ	–25°C to +85°C	10-Pin Metal Header Package [TO-100]	H-10
AD632BD	–25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632BDZ	–25°C to +85°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632BHZ	–25°C to +85°C	10-Pin Metal Header Package [TO-100]	H-10
AD632SD	–55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632SH	–55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10
AD632SH/883B	–55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10
AD632TD	–55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632TD/883B	–55°C to +125°C	14-Lead Side-Brazed Ceramic Dual In-Line Package [SBDIP]	D-14
AD632TH	–55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10
AD632TH/883B	–55°C to +125°C	10-Pin Metal Header Package [TO-100]	H-10

¹ Z = RoHS Compliant Part.

NOTES